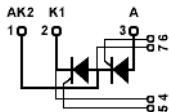


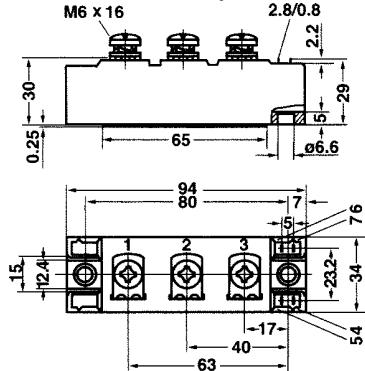
CTT181

Thyristor-Thyristor Modules



Type	V_{RSM} V_{DSM}	V_{RRM} V_{DRM}
	V	V
CTT181GK08	900	800
CTT181GK12	1300	1200
CTT181GK14	1500	1400
CTT181GK16	1700	1600
CTT181GK18	1900	1800

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
I_{TRMS} , I_{FRMS} I_{TAVM} , I_{FAVM}	$T_{VJ}=T_{VJM}$ $T_c=85^\circ\text{C}$; 180° sine	300 181	A
I_{TSM} , I_{FSM}	$T_{VJ}=45^\circ\text{C}$ $V_R=0$	6000 6400	A
	$T_{VJ}=T_{VJM}$ $V_R=0$	5250 5600	
$\int i^2 dt$	$T_{VJ}=45^\circ\text{C}$ $V_R=0$	180000 170000	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$	137000 128000	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ $f=50\text{Hz}$, $t_p=200\mu\text{s}$ $V_D=2/3V_{DRM}$ $I_G=0.5\text{A}$ $dI/dt=0.5\text{A}/\mu\text{s}$	150 500	$\text{A}/\mu\text{s}$
	$V_{DR}=2/3V_{DRM}$ $R_{GK}=\infty$; method 1 (linear voltage rise)	1000	
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$	120 60	W
P_{GAV}		8	W
V_{RGM}		10	V
T_{VJ} T_{VJM} T_{stg}		-40...+125 125 -40...+125	$^\circ\text{C}$
V_{ISOL}	50/60Hz, RMS $I_{ISOL}\leq 1\text{mA}$	3000 3600	V~
M_d	Mounting torque (M6) Terminal connection torque (M6)	2.25-2.75/20-25 4.5-5.5/40-48	Nm/lb.in.
Weight	Typical including screws	125	g

D E E C o r p .

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Thyristor-Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_{RRM}, I_{DRM}	$T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$	10	mA
V_T, V_F	$I_T, I_F=300A; T_{VJ}=25^\circ C$	1.25	V
V_{TO}	For power-loss calculations only ($T_{VJ}=125^\circ C$)	0.88	V
r_T		1.15	$m\Omega$
V_{GT}	$V_D=6V; T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	2.5 2.6	V
I_{GT}	$V_D=6V; T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	150 200	mA
V_{GD}	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	0.2	V
I_{GD}		10	mA
I_L	$T_{VJ}=25^\circ C; t_p=30\mu s; V_D=6V$ $I_G=0.5A; dI/dt=0.5A/\mu s$	300	mA
I_H	$T_{VJ}=25^\circ C; V_D=6V; R_{GK}=\infty$	200	mA
t_{gd}	$T_{VJ}=25^\circ C; V_D=1/2V_{DRM}$ $I_G=0.5A; dI/dt=0.5A/\mu s$	2	us
t_q	$T_{VJ}=T_{VJM}; I_T=300A; t_p=200\mu s; -dI/dt=10A/\mu s$ $V_R=100V; dv/dt=20V/\mu s; V_D=2/3V_{DRM}$	typ. 150	us
Q_s	$T_{VJ}=T_{VJM}; I_T, I_F=300A; -dI/dt=50A/\mu s$	550	uC
I_{RM}		235	A
R_{thJC}	per thyristor/diode; DC current per module	0.155 0.0775	K/W
R_{thJK}	per thyristor/diode; DC current per module	0.225 0.1125	K/W
ds	Creeping distance on surface	12.7	mm
da	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s^2

FEATURES

- * International standard package
- * Direct copper bonded Al₂O₃-ceramic base plate
- * Planar passivated chips
- * Isolation voltage 3600 V~
- * UL registered, E 72873
- * Keyed gate/cathode twin pins

APPLICATIONS

- * Motor control
- * Power converter
- * Heat and temperature control for industrial furnaces and chemical processes
- * Lighting control
- * Contactless switches

ADVANTAGES

- * Space and weight savings
- * Simple mounting
- * Improved temperature and power cycling
- * Reduced protection circuits

D E E C o r p .

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Thyristor-Thyristor Modules

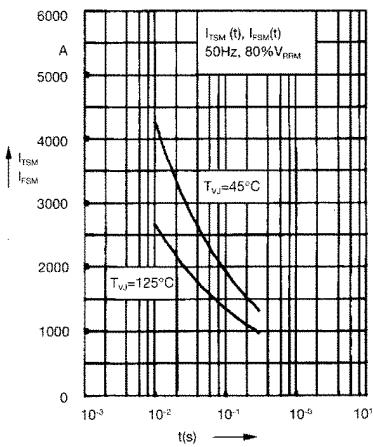


Fig. 1 Surge overload current
 I_{TSM}, I_{FSM} : Crest value, t : duration

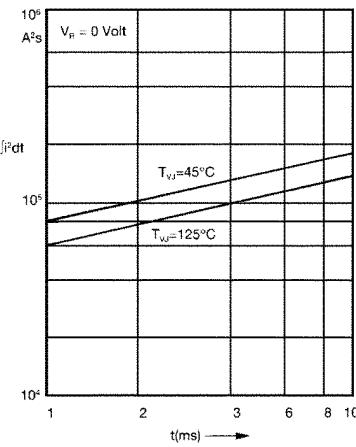


Fig. 2 $\int i^2 t$ versus time (1-10 ms)

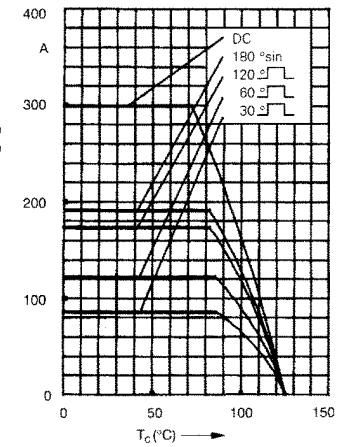


Fig. 2a Maximum forward current at case temperature

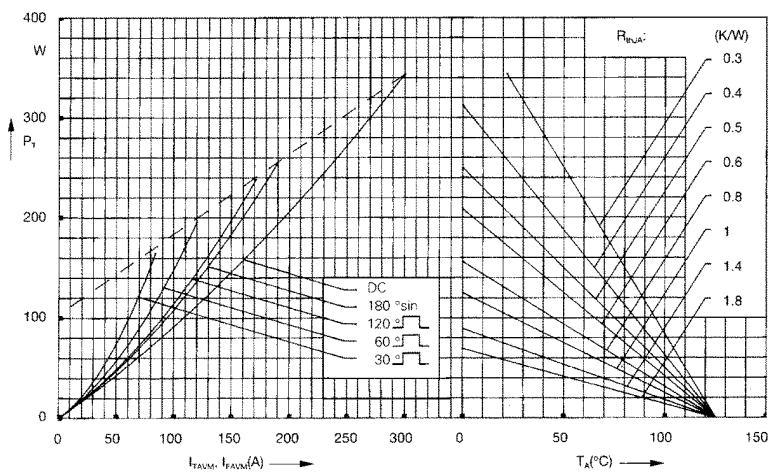


Fig. 3 Power dissipation versus on-state current and ambient temperature (per thyristor or diode)

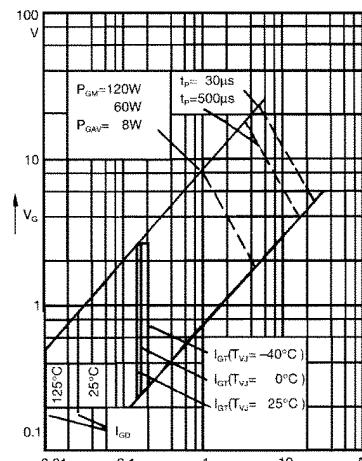


Fig. 4 Gate trigger characteristics

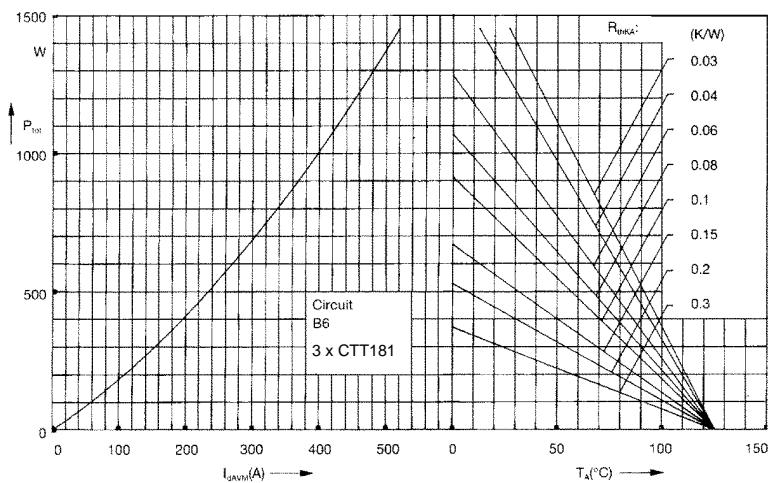


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

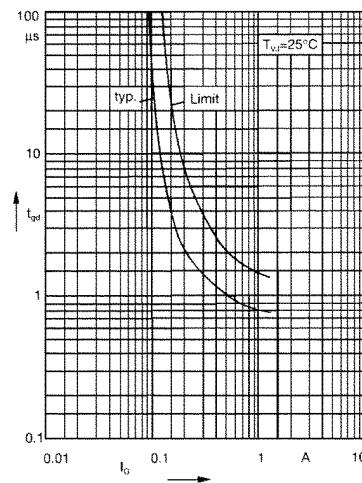


Fig. 6 Gate trigger delay time

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Thyristor-Thyristor Modules

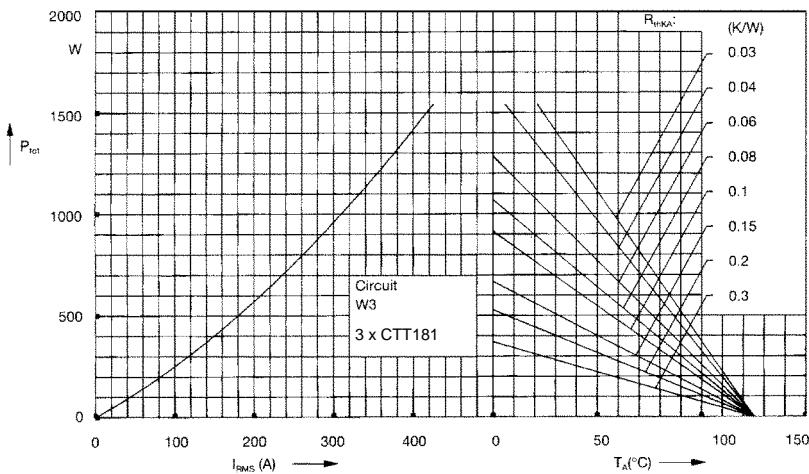


Fig. 7 Three phase AC-controller:
Power dissipation versus RMS
output current and ambient
temperature

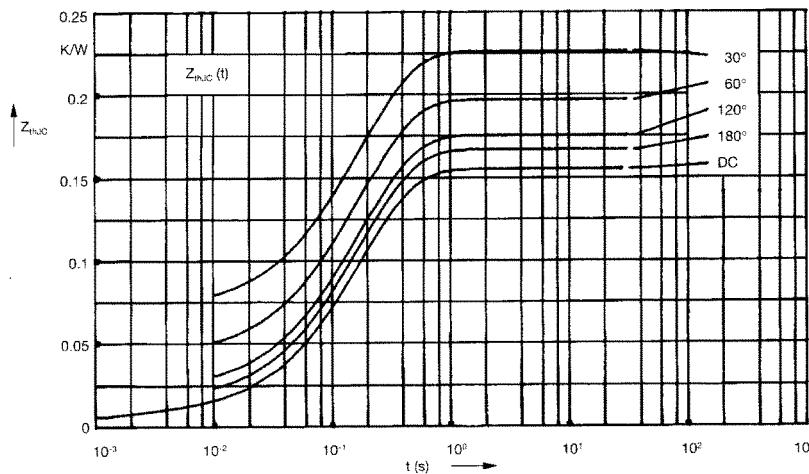


Fig. 8 Transient thermal impedance
junction to case (per thyristor or
diode)

d	R_{thJC} (K/W)
DC	0.155
180°C	0.167
120°C	0.176
60°C	0.197
30°C	0.227

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0072	0.001
2	0.0188	0.08
3	0.129	0.2

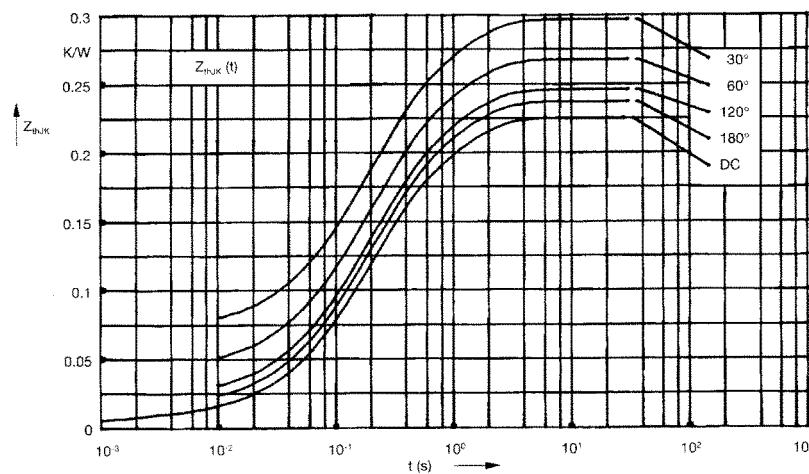


Fig. 9 Transient thermal impedance
junction to heatsink (per thyristor or
diode)

d	R_{thJK} (K/W)
DC	0.225
180°C	0.237
120°C	0.246
60°C	0.267
30°C	0.297

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0072	0.001
2	0.0188	0.08
3	0.129	0.2
4	0.07	1.0